DESCRIPTION

The SPN3414 is the N-Channel logic enhancement mode power field effect transistors are produced using high cell density, DMOS trench technology.

This high density process is especially tailored to minimize on-state resistance.

These devices are particularly suited for low voltage application such as cellular phone and notebook computer power management and other battery powered circuits where high-side switching, and low in-line power loss are needed in a very small outline surface mount package.

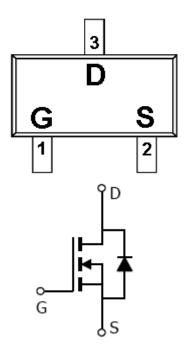
FEATURES

- 20V/4.0A,RDS(ON)= $55m\Omega$ @VGS=4.5V
- 20V/3.4A,RDS(ON)= $70m\Omega$ @VGS=2.5V
- 20V/2.8A,RDS(ON)= $90m\Omega$ @VGS=1.8V
- ◆ Super high density cell design for extremely low RDS (ON)
- Exceptional on-resistance and maximum DC current capability
- ◆ SOT-23-3L package design

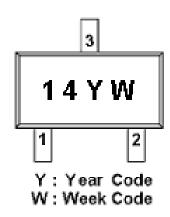
APPLICATIONS

- Power Management in Note book
- Portable Equipment
- Battery Powered System
- DC/DC Converter
- Load Switch
- DSC
- LCD Display inverter

PIN CONFIGURATION(SOT-23-3L)



PART MARKING



PIN DESCRIPTION						
Pin	Symbol	Description				
1	G	Gate				
2	S	Source				
3	D	Drain				

ORDERING INFORMATION

Part Number	Package	Part Marking		
SPN3414S23RGB	SOT-23-3L	14		

% Week Code : A ~ Z(1 ~ 26); a ~ z(27 ~ 52)

※ SPN3414S23RGB: Tape Reel; Pb − Free; Halogen − Free

ABSOULTE MAXIMUM RATINGS

(Ta=25°C Unless otherwise noted)

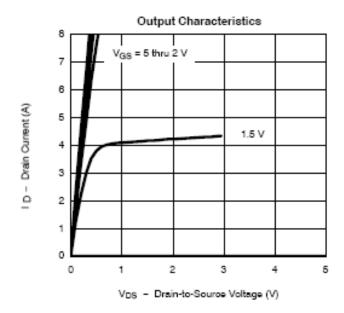
Parameter		Symbol	Typical	Unit	
Drain-Source Voltage		Vdss	20	V	
Gate –Source Voltage		VGSS	±12	V	
Continuous Drain Current(T _J =150°C)	Ta=25°C	ID	4.0	A	
Continuous Diani Current(13–130 C)	Ta=70°C		3.4	A	
Pulsed Drain Current		Ірм	10	A	
Continuous Source Current(Diode Conduction)		Is	1.6	A	
Power Dissinction	TA=25°C	Dro	1.25	W	
Power Dissipation	Ta=70°C	PD	0.8		
Operating Junction Temperature		ιΤ	-55/150	°C	
Storage Temperature Range		Tstg	-55/150	°C	
Thermal Resistance-Junction to Ambient		RθJA	105	°C/W	

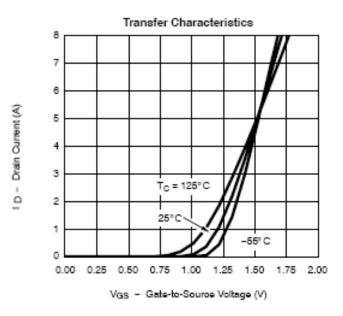
ELECTRICAL CHARACTERISTICS

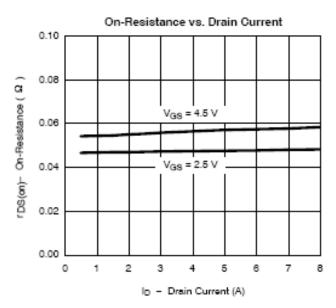
(TA=25°C Unless otherwise noted)

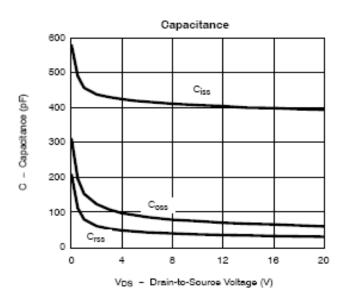
Parameter	Symbol	Conditions	Min.	Тур	Max.	Unit
Static		1	1		ı	
Drain-Source Breakdown Voltage	V(BR)DSS	VGS=0V,ID=250uA	20			V
Gate Threshold Voltage	VGS(th)	Vds=Vgs,Id=250uA	0.4		1.0	
Gate Leakage Current	Igss	VDS=0V,VGS=±12V			±100	nA
Zero Gate Voltage Drain Current		VDS=20V,VGS=0V			1	uA
	Idss	V _{DS} =20V,V _{GS} =0V T _J =55°C			5	
On-State Drain Current	ID(on)	$V_{DS} \le 5V, V_{GS} = 4.5V$	6			A
		Vgs=4.5V,Id=4.0A		0.040	0.055	Ω
Drain-Source On-Resistance	RDS(on)	Vgs=2.5V,Id=3.4A		0.055	0.070	
		Vgs=1.8V,Id=2.8A		0.075	0.090	
Forward Transconductance	gfs	VDS=5V,ID=-3.6A		10		S
Diode Forward Voltage	Vsd	Is=1.6A,VGS=0V		0.8	1.2	V
Dynamic						
Total Gate Charge	Qg			4.8	8	nC
Gate-Source Charge	Qgs	VDS=6V,VGS=4.5V ID=2.8A		1.0		
Gate-Drain Charge	Qgd	10-2.071		1.0		
Input Capacitance	Ciss			485		pF
Output Capacitance	Coss	VDS=6V,VGS=0V f=1MHz		85		
Reverse Transfer Capacitance	Crss			40		
Turn-On Time	td(on)			8	14	nS
	t r	V _{DD} =6V,R _L =6Ω		12	18	
T Off T'	td(off)	$I_D=1.0A,V_{GEN}=4.5V$ $R_G=6\Omega$		30	35	
Turn-Off Time	tf			12	16	

TYPICAL CHARACTERISTICS

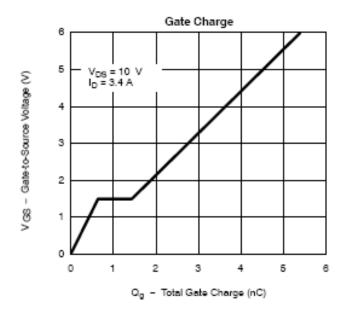


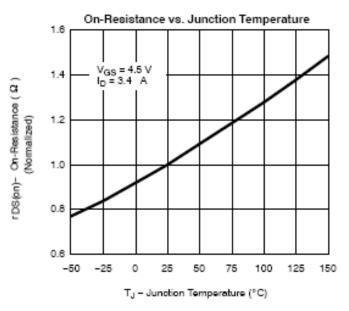


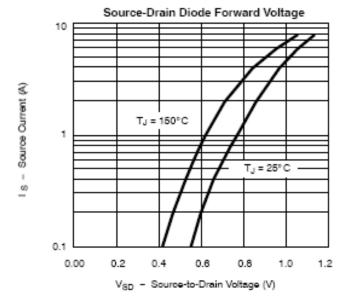


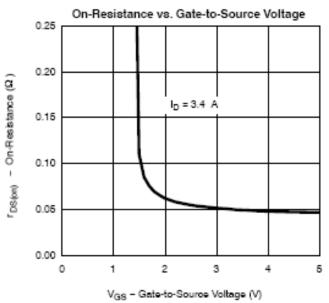


TYPICAL CHARACTERISTICS

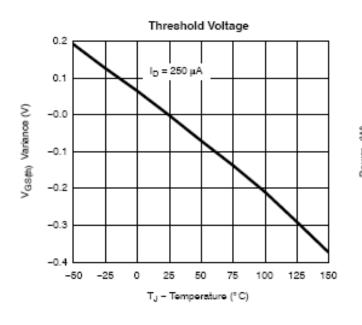


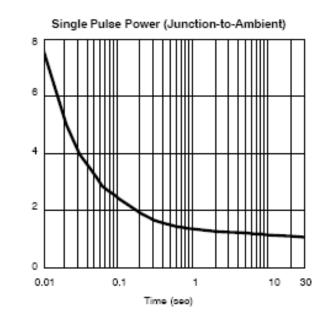


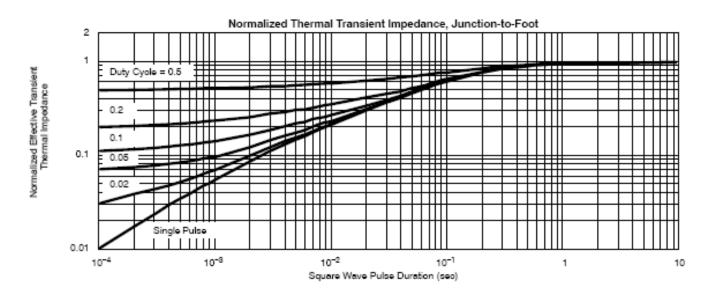




TYPICAL CHARACTERISTICS







Information provided is alleged to be exact and consistent. SYNC Power Corporation presumes no responsibility for the penalties of use of such information or for any violation of patents or other rights of third parties which may result from its use. No license is granted by allegation or otherwise under any patent or patent rights of SYNC Power Corporation. Conditions mentioned in this publication are subject to change without notice. This publication surpasses and replaces all information previously supplied. SYNC Power Corporation products are not authorized for use as critical components in life support devices or systems without express written approval of SYNC Power Corporation.

© The SYNC Power logo is a registered trademark of SYNC Power Corporation
© 2020 SYNC Power Corporation – Printed in Taiwan – All Rights Reserved
SYNC Power Corporation
7F-2, No.3-1, Park Street
NanKang District (NKSP), Taipei, Taiwan, 115, R.O.C
Phone: 886-2-2655-8178
Fax: 886-2-2655-8468

© http://www.syncpower.com